Vishay High Power Products

HEXFRED[®] Ultrafast Soft Recovery Diode, 8 A



Base cathode

Cathode

PRODUCT SUMMARY

 V_R

V_F at 8 A at 25 °C

I_{F(AV)}

t_{rr} (typical)

T_{.1} (maximum)

Q_{rr} (typical)

dl_{(rec)M}/dt (typical)

I_{RRM}

TO-220AC

З

600 V

1.7 V

8 A

18 ns

150 °C

65 nC

240 A/µs

5.0 A

Anode

FEATURESUltrafast recovery

- Ultrasoft recovery
- Very low I_{RBM}
- Very low Q_{rr}
- · Specified at operating conditions
- Lead (Pb)-free
- Designed and qualified for industrial level

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

HFA08TB60 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 8 A continuous current, the HFA08TB60 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current ($I_{\mbox{\scriptsize RRM}}$) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA08TB60 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Cathode to anode voltage	V _R		600	V				
Maximum continuous forward current	۱ _F	T _C = 100 °C	8					
Single pulse forward current	I _{FSM}		60	А				
Maximum repetitive forward current	I _{FRM}		24					
Maximum power discinction	Б	T _C = 25 °C	36	14/				
	гD	T _C = 100 °C	14	vv				
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	°C				

* Pb containing terminations are not RoHS compliant, exemptions may apply

HFA08TB60PbF



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ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		600	-	-	
Maximum forward voltage	V _{FM}	I _F = 8.0 A	See fig. 1	-	1.4	1.7	V
		I _F = 16 A		-	1.7	2.1	
		I _F = 8.0 A, T _J = 125 °C		-	1.4	1.7	
Maximum reverse		$V_{R} = V_{R}$ rated	See fig. 0	-	0.3	5.0	μΑ
leakage current	IRM	$T_J = 125 \ ^{\circ}C, V_R = 0.8 \ x \ V_R$ rated	See lig. 2	-	100	500	
Junction capacitance	CT	V _R = 200 V	See fig. 3	-	10	25	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body			8.0	-	nH

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
	t _{rr}	$I_F = 1.0 \text{ A}, \text{ dI}_F/\text{dt} = 200$	A/ μ s, V _R = 30 V	-	18	-	ns	
Reverse recovery time	t _{rr1}	T _J = 25 °C	I _F = 8.0 A dI _F /dt = 200 A/μs V _R = 200 V	-	37	55		
	t _{rr2}	T _J = 125 °C		-	55	90		
Peak recovery current	I _{RRM1}	T _J = 25 °C		-	3.5	5.0	A nC	
	I _{RRM2}	T _J = 125 °C		-	4.5	8.0		
Reverse recovery charge	Q _{rr1}	T _J = 25 °C		-	65	138		
	Q _{rr2}	T _J = 125 °C		-	124	360		
Peak rate of fall of recovery current during $t_{\mbox{\scriptsize b}}$	dl _{(rec)M} /dt1	$T_J = 25 \ ^{\circ}C$		-	240	-	A/µs	
	dl _{(rec)M} /dt2	T _J = 125 °C		-	210	-		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C	
Thermal resistance, junction to case	R _{thJC}		-	-	3.5		
Thermal resistance, junction to ambient	R _{thJA}	R _{thJA} Typical socket mount		-	80	K/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.5	-		
Woight			-	2.0	-	g	
weight			-	0.07	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)	
Marking device		Case style TO-220AC		HFA0	BTB60		

Outline Dimensions

Vishay High Power Products

D²PAK

DIMENSIONS in millimeters and inches

VISHAY



SVMBOI	MILLIMETERS		INC	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	IETERS I		HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D1	6.86	-	0.270	-	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	6.22	-	0.245	-	3	
е	2.54	BSC	0.100	BSC		
Н	14.61	15.88	0.575	0.625		
L	1.78	2.79	0.070	0.110		
L1	-	1.65	-	0.066	3	
L2	1.27	1.78	0.050	0.070		
L3	0.25 BSC		0.010	BSC		
L4	4.78	5.28	0.188	0.208		

Notes

 $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
(3) The outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

 $^{\rm (5)}$ Datum A and B to be determined at datum plane H $^{\rm (5)}$

⁽⁶⁾ Controlling dimension: inch

⁽⁷⁾ Outline conforms to JEDEC outline TO-263AB



Packaging Information

Vishay High Power Products

D²PAK



TAPE AND REEL INFORMATION in millimeters (inches)

Section Y - Y

Notes

- ⁽¹⁾ 10 sprocket hole pitch cumulative tolerance ± 0.02
- ⁽²⁾ Camber not to exceed 1 mm in 100 mm
- ⁽³⁾ Material: conductive black styrenic alloy
- $^{(4)}$ K₀ measured from a plane on the inside bottom of the pocket to the top surface of the carrier
- ⁽⁵⁾ Measured from centerline of sprocket hole to centerline of pocket
- (6) Vendor: (optional)
- (7) Must also meet requirements of EIA standard # EIA-481A taping of surface mount components for automatic placement
- $^{(8)}$ Surface resistivity of molded material must measure less or equal to 10⁶ Ω per square. Measured in accordance to procedure given in ASTM D-257 and ASTM D-991
- ⁽⁹⁾ Total length per reel must be 45 m

 $^{(10)} \bigcirc$ critical